

SM4001FL - SM4007FL SURFACE MOUNT RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 1.0 A

Features

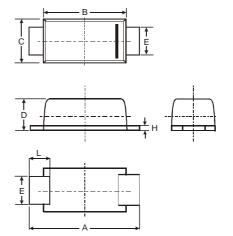
- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Low Power Loss
- Built-in Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: JEDEC SOD-123FL molded plastic body over passivated chip
- Terminals: Plated axial leads,
- solderable per MIL-STD-750, Method 2026
 Polarity: Color band denotes cathode end
- Mounting Position : Any
- Weight: 0.0007 ounce, 0.02 grams







| SOD-123FL | | | | | | | | | |
|----------------------|-------|------|------|--|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | | |
| Α | 3.58 | 3.72 | 3.65 | | | | | | |
| В | 2.72 | 2.78 | 2.75 | | | | | | |
| С | 1.77 | 1.83 | 1.80 | | | | | | |
| D | 1.02 | 1.08 | 1.05 | | | | | | |
| Е | 0.097 | 1.03 | 1.00 | | | | | | |
| Н | 0.13 | 0.17 | 0.15 | | | | | | |
| Ĺ | 0.53 | 0.57 | 0.55 | | | | | | |
| All Dimensions in mm | | | | | | | | | |

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | SOD4001FL | SM4002FL | SM4003FL | SM4004FL | SM4005FL | SM4006FL | SM4007FL | Unit |
|---|--------------------|----------------|----------|----------|----------|----------|----------|----------|------|
| | Marking | D1 | D2 | D3 | D4 | D5 | D6 | D7 | Unit |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | VRRM VRWM VR | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | VR(RMS) | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Rectified Output Current @T _L = 100°C | lo | 1.0 | | | | | | | А |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | İFSM | 30 | | | | | | | А |
| Forward Voltage @I _F = 1.0A | VFM | 1.10 | | | | | | | V |
| | İRM | IRM 5.0 200 | | | | | μA | | |
| Reverse Recovery Time (Note 1) | trr | 2.5 | | | | | | | μS |
| Typical Junction Capacitance (Note 2) | Cj | 15 | | | | | | | pF |
| Typical Thermal Resistance (Note 3) | RθJL | 30 | | | | | | | K/W |
| Operating and Storage Temperature Range | Tj, Tstg | -65 to +175 | | | | | | | °C |

Note: 1. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$,

- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
- 3. Mounted on P.C. Board with 8.0mm² land area.



